NSN 5961-01-093-2579

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-093-2579 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.150 inches and 0.160 inches Overall Diameter: Between 0.375 inches and 0.385 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 2.50 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator: Terminal Type And Quantity:** 3 pin **Specification Data:** 80131-release5296 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

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